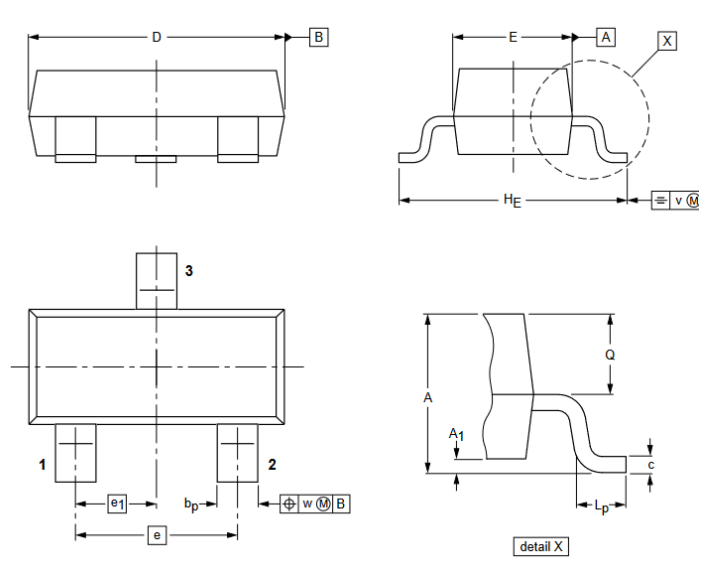


Silicon SMD NPN Epitaxial Transistors

Primary characteristics			
Symbol	Parameter	Value	Unit
V_{CB0}	Collector-base voltage	50	V
V_{CE0}	Collector-emitter voltage	45	V
V_{EB0}	Emitter-base voltage	5	V
P_C	Collector power dissipation	300	mW

Features

- **SOT-23** case for easy automatic insertion.
- Pb-free and **RoHS** compliant
- Epitaxial planar die construction
- Complementary **PNP** type available (**BC807**)

Case dimensions													
 <p style="text-align: center;">1 – Base; 2 – Emitter; 3 – Collector</p>													
SOT-23 (TO-236AB)													
Unit	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.0 ±0.1	0.1	0.43 ±0.05	0.12 ±0.03	2.9 ±0.1	1.3 ±0.1	1.9	0.95	2.3 ±0.2	0.3 ±0.15	0.5 ±0.05	0.2	0.1

Part numbering system	
BC817-	25
↓	↓
Series code	H _{FE} classification (see: Classification of h_{FE(1)})

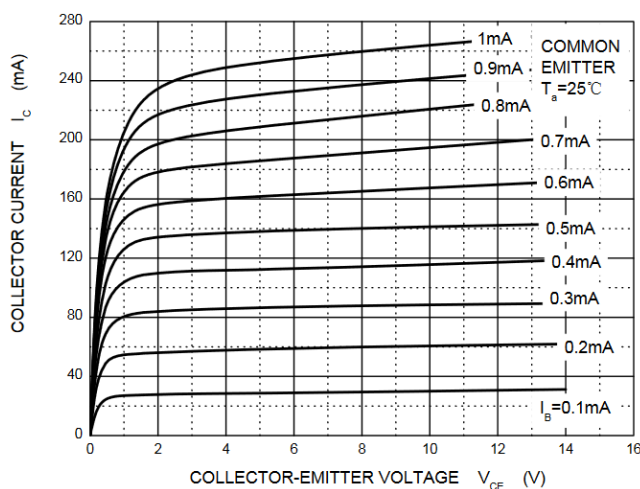
Electrical characteristics and maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Test conditions	Value		Unit
			Min	Max	
Collector-base voltage	V_{CBO}	$I_C = 10\mu\text{A}, I_E = 0$	50		V
Collector-emitter voltage	V_{CEO}	$I_C = 10\mu\text{A}, I_B = 0$	45		V
Emitter-base voltage	V_{EBO}	$I_E = 1\mu\text{A}, I_C = 0$	5		V
Collector cut-off current	I_{CBO}	$V_{CB} = 45\text{V}, I_E = 0$		0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 4\text{V}, I_C = 0$		0.1	μA
Collector current	I_C			500	mA
Collector power dissipation	P_C			300	mW
DC current gain	$h_{FE(1)}$	$V_{CE} = 1\text{V}, I_C = 100\text{mA}$	100	600	
	$h_{FE(2)}$	$V_{CE} = 1\text{V}, I_C = 500\text{mA}$	40		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}$		0.7	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 500\text{mA}, I_B = 50\text{mA}$		1.2	V
Transition frequency	f_T	$V_{CE} = 5\text{V}, I_C = 10\text{mA}$ $f = 100\text{MHz}$	100		MHz
Junction temperature	T_j			150	$^\circ\text{C}$
Storage temperature range	T_s		-55	150	$^\circ\text{C}$
Thermal resistance junction to ambient air ¹⁾	R_{thA}			417	$^\circ\text{C}/\text{W}$

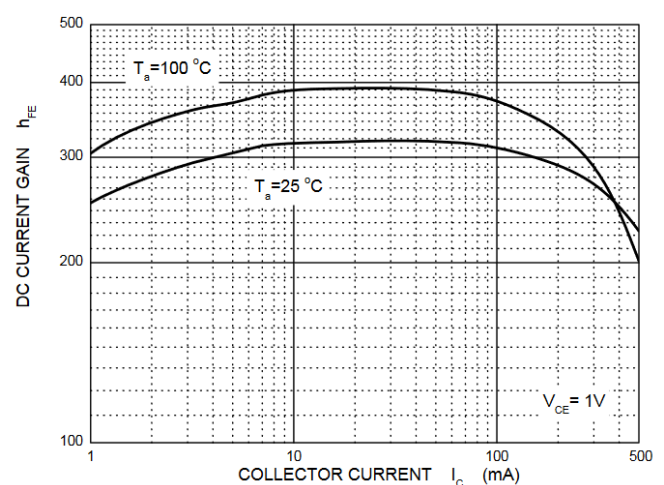
Classification of $h_{FE(1)}$

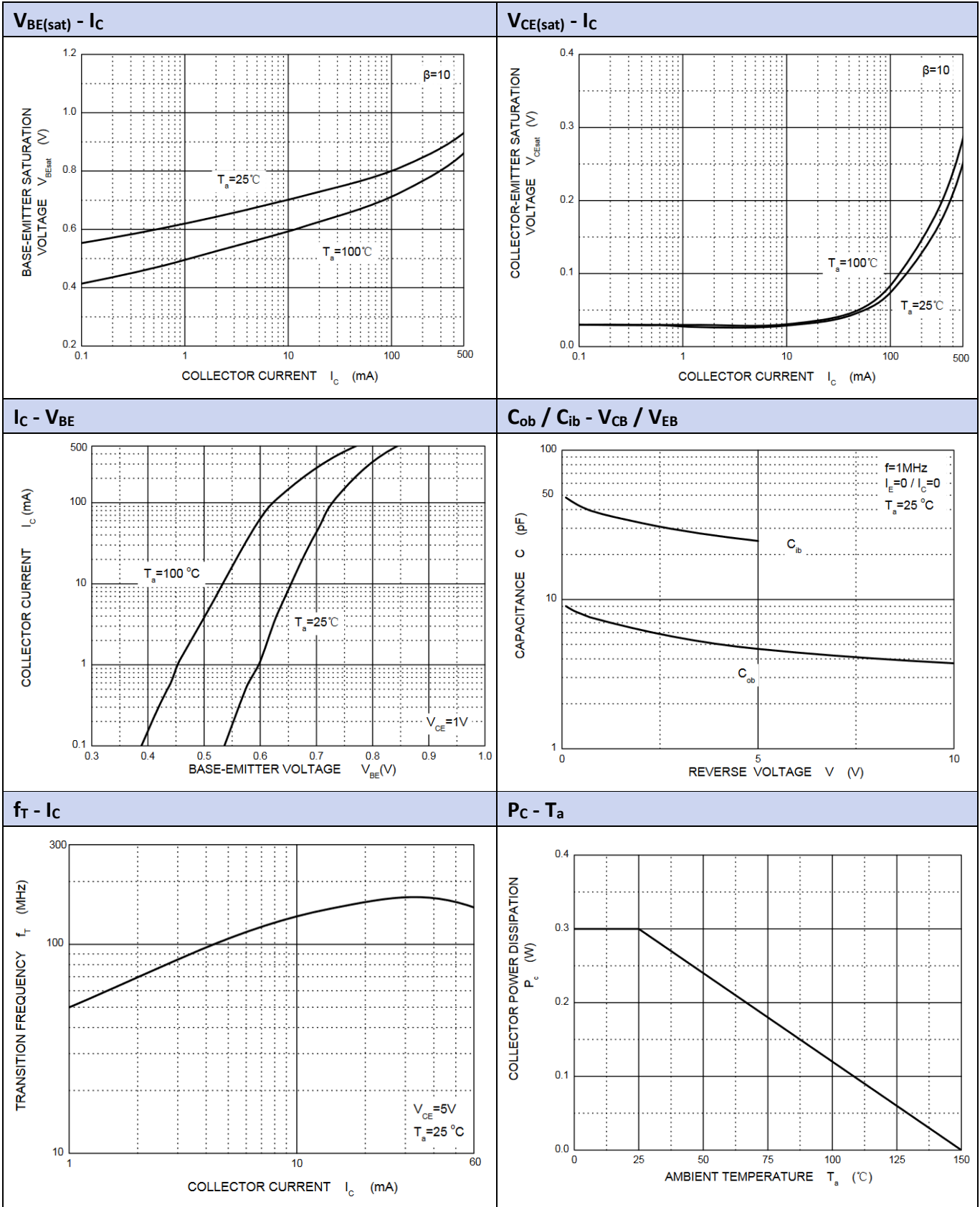
Part number	Range	
	Min	Max
BC807-16	100	250
BC807-25	160	400
BC807-40	250	600

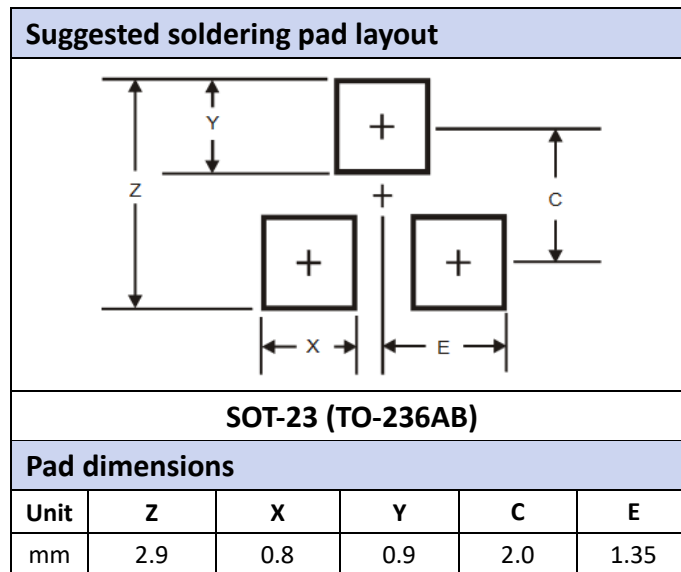
Static characteristic



$H_{FE} - I_C$







Ordering information			
Part Number	Package	Shipping Quantity	Dimensions
BC817-16 ~ BC817-40	SOT-23 (TO-236AB)	3000 pcs / reel 144 000 pcs / box	--- 400 x 370 x 270 mm

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